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# HMC508\* Product Page Quick Links

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- HMC508 Data Sheet

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- Package/Assembly Qualification Test Report: 32L 5x5mm QFN Package (QTR: 10009 REV: 05)
- Package/Assembly Qualification Test Report: LP3, LP4, LP5 & LP5G (QTR: 2014-00145)
- Package/Assembly Qualification Test Report: Plastic Encapsulated QFN (QTR: 05006 REV: 02)
- Semiconductor Qualification Test Report: GaAs HBT-A (QTR: 2013-00228)

### **Technical Articles**

- High Performance SiGe PLLs Pair with Low Phase Noise GaAs VCOs for Microwave Radio

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# HMC508LP5 / 508LP5E

## MMIC VCO w/ HALF FREQUENCY OUTPUT 7.3 - 8.2 GHz

### Typical Applications

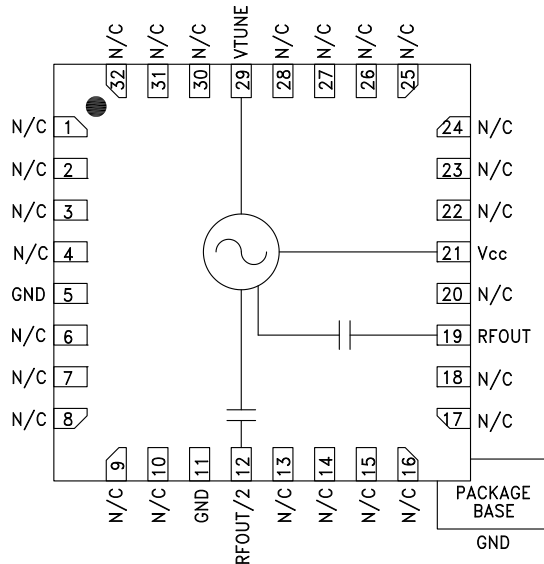
Low noise MMIC VCO w/Half Frequency, for:

- VSAT Radio
- Point to Point/Multi-Point Radio
- Test Equipment & Industrial Controls
- Military End-Use

### Features

- Dual Output:  $F_o = 7.3 - 8.2$  GHz  
 $F_o/2 = 3.65 - 4.1$  GHz
- Pout: +15.0 dBm
- Phase Noise: -116 dBc/Hz @100 kHz Typ.
- No External Resonator Needed
- 32 Lead 5x5mm SMT Package: 25mm<sup>2</sup>

### Functional Diagram

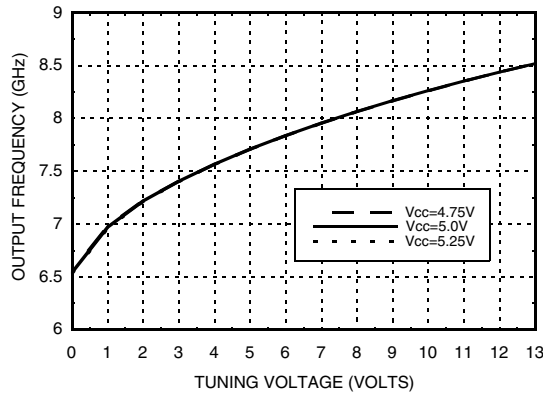
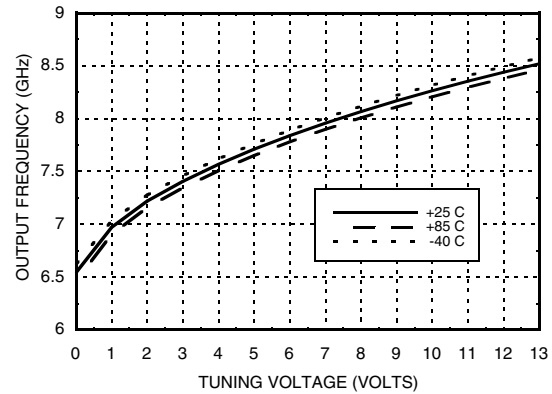
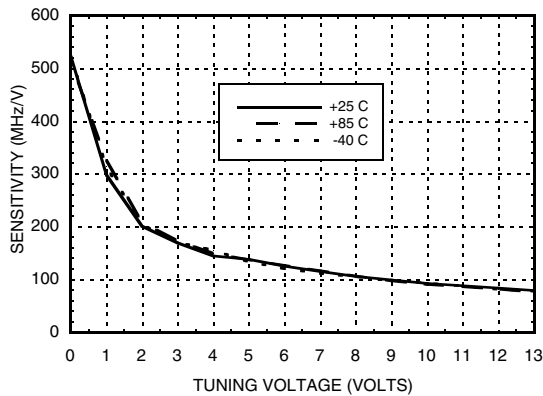
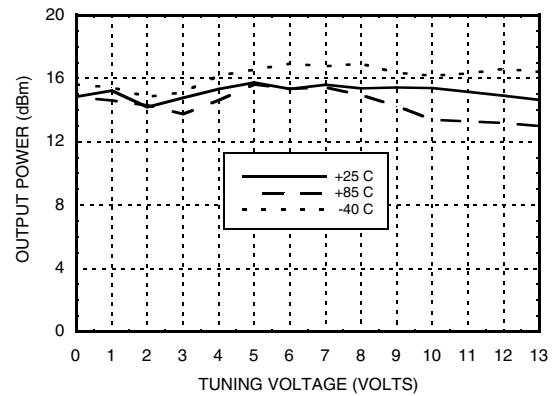
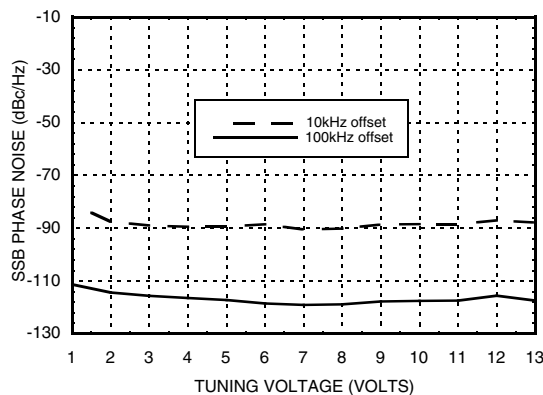
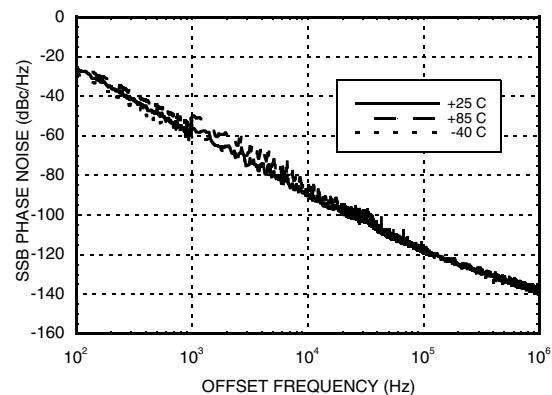


### General Description

The HMC508LP5 & HMC508LP5E are GaAs InGaP Heterojunction Bipolar Transistor (HBT) MMIC VCOs. The HMC508LP5 & HMC508LP5E integrate resonators, negative resistance devices, varactor diodes and feature a half frequency output. The VCO's phase noise performance is excellent over temperature, shock, and process due to the oscillator's monolithic structure. Power output is +15 dBm typical from a +5V supply. The voltage controlled oscillator is packaged in a leadless QFN 5x5 mm surface mount package, and requires no external matching components.

### Electrical Specifications, $T_A = +25^\circ C$ , $V_{cc} = +5V$

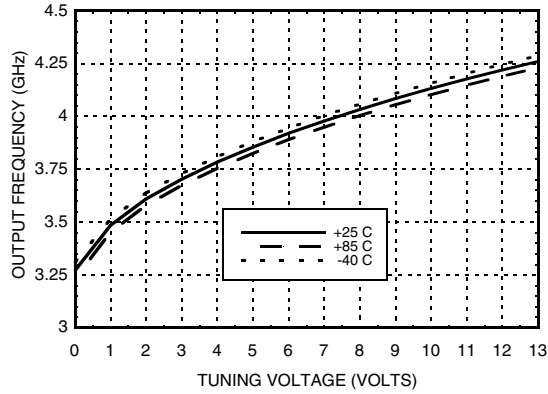
Parameter	Min.	Typ.	Max.	Units	
Frequency Range	$F_o$ $F_o/2$	7.3 - 8.2 3.65 - 4.1		GHz GHz	
Power Output	RFOUT RFOUT/2	+12 +4	+17 +10	dBm dBm	
SSB Phase Noise @ 100 kHz Offset, $V_{tune} = +5V$ @ RFOUT		-116		dBc/Hz	
Tune Voltage	$V_{tune}$	2	13	V	
Supply Current ( $I_{cc}$ ) ( $V_{cc} = +5.0V$ )		200	240	280	mA
Tune Port Leakage Current ( $V_{tune} = 13V$ )			10	$\mu A$	
Output Return Loss		2		dB	
Harmonics/Subharmonics	1/2 2nd 3rd		40 20 35	dBc dBc dBc	
Pulling (into a 2.0:1 VSWR)			8	MHz pp	
Pushing @ $V_{tune} = 5V$			10	MHz/V	
Frequency Drift Rate			1.0	MHz/ $^\circ C$	

**Frequency vs. Tuning Voltage,  $T = 25^{\circ}\text{C}$** 

**Frequency vs. Tuning Voltage,  $V_{cc} = +5\text{V}$** 

**Sensitivity vs. Tuning Voltage,  $V_{cc} = +5\text{V}$** 

**Output Power vs. Tuning Voltage,  $V_{cc} = +5\text{V}$** 

**SSB Phase Noise vs. Tuning Voltage**

**SSB Phase Noise @  $V_{tune} = +5\text{V}$** 


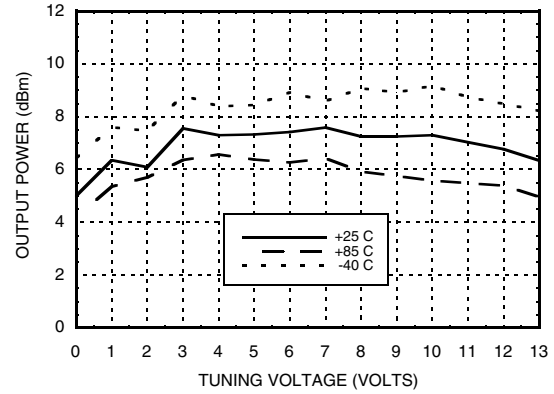


## MMIC VCO w/ HALF FREQUENCY OUTPUT 7.3 - 8.2 GHz

**RFOUT/2 Frequency  
vs. Tuning Voltage, Vcc= +5V**



**RFOUT/2 Output Power  
vs. Tuning Voltage, Vcc= +5V**



### Absolute Maximum Ratings

Vcc	+5.5 Vdc
Vtune	0 to +15V
Junction Temperature	135 °C
Continuous Pdiss (T=85 °C) (derate 28 mW/C above 85 °C)	1.4 W
Thermal Resistance (junction to ground paddle)	35 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 1A

### Typical Supply Current vs. Vcc

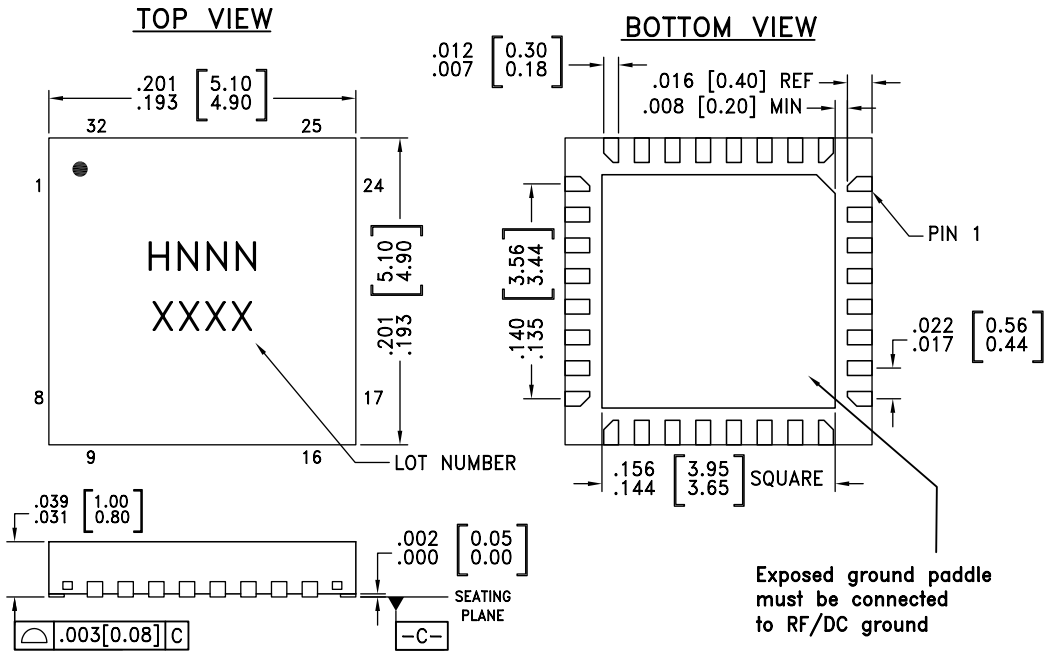
Vcc (V)	Icc (mA)
4.75	220
5.0	240
5.25	260

Note: VCO will operate over full voltage range shown above.



**ELECTROSTATIC SENSITIVE DEVICE  
OBSERVE HANDLING PRECAUTIONS**

### Outline Drawing



- NOTES:
1. LEADFRAME MATERIAL: COPPER ALLOY
  2. DIMENSIONS ARE IN INCHES [MILLIMETERS]
  3. LEAD SPACING TOLERANCE IS NON-CUMULATIVE.
  4. PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM.  
PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM.
  5. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
  6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.
  7. REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED LAND PATTERN.

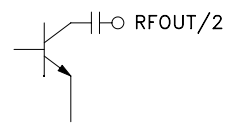
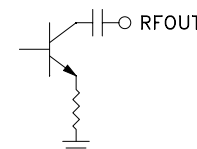
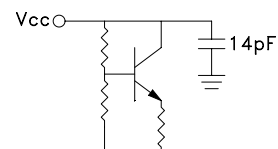
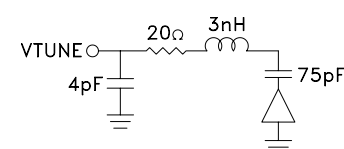

### Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking <sup>[3]</sup>
HMC508LP5	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL3 <sup>[1]</sup>	H508 XXXX
HMC508LP5E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL3 <sup>[2]</sup>	H508 XXXX

[1] Max peak reflow temperature of 235 °C  
 [2] Max peak reflow temperature of 260 °C  
 [3] 4-Digit lot number XXXX

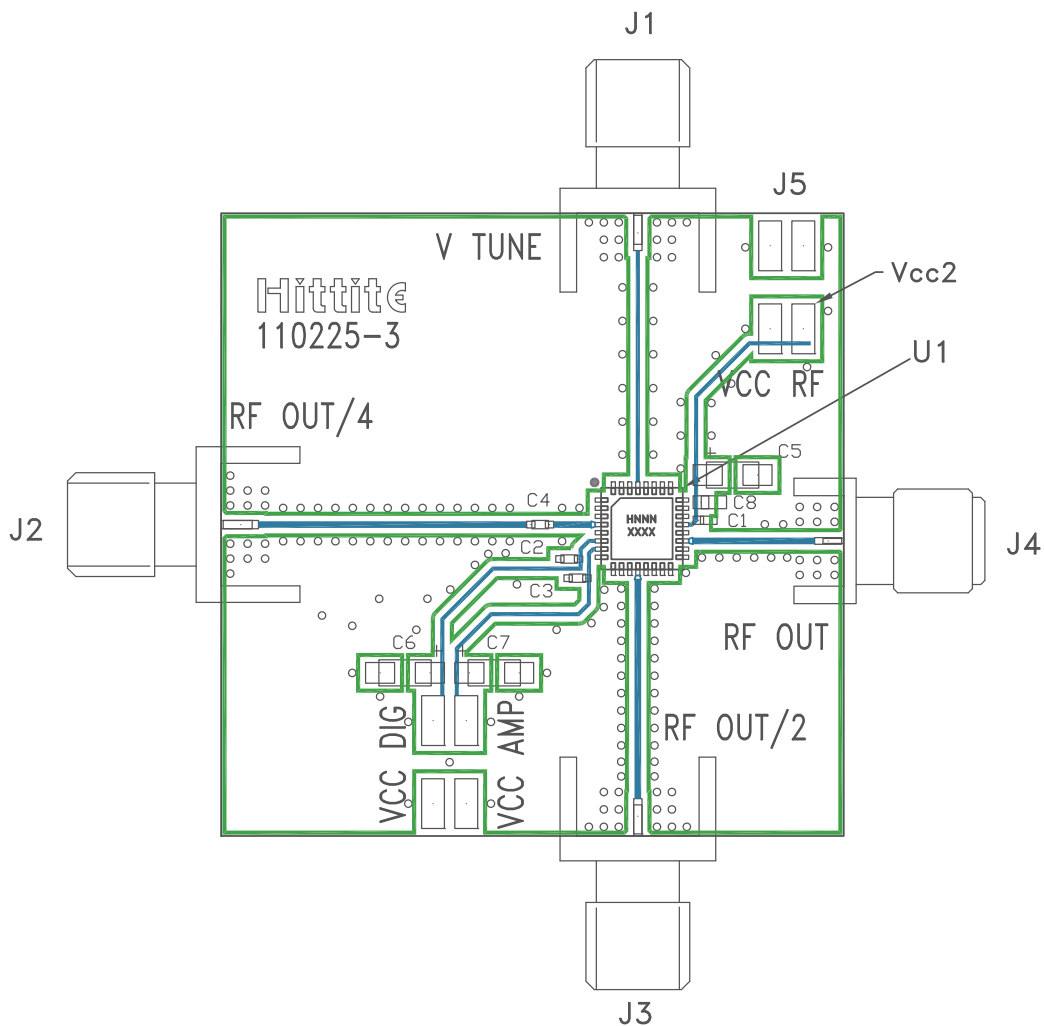


### Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1 - 4, 6 - 10, 13 - 18, 20, 22 - 28, 30 - 32	N/C	No Connection. These pins may be connected to RF/ DC ground. Performance will not be affected.	
12	RFOUT/2	Half frequency output (AC coupled).	
19	RFOUT	RF output (AC coupled).	
21	Vcc	Supply Voltage, +5V	
29	VTUNE	Control Voltage Input. Modulation port bandwidth dependent on drive source impedance.	
5, 11, Paddle	GND	Package bottom has an exposed metal paddle that must be connected to RF/DC ground.	



### Evaluation PCB



### List of Materials for Evaluation PCB 110227 [1]

Item	Description
J1 - J4	PCB Mount SMA RF Connector
J5	2 mm DC Header
C1 - C3	100 pF Capacitor, 0402 Pkg.
C4	1,000 pF Capacitor, 0402 Pkg.
C5 - C7	2.2 $\mu$ F Tantalum Capacitor
U1	HMC508LP5(E) VCO
PCB [2]	110225 Eval Board

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Arlon 25FR

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and backside ground paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.